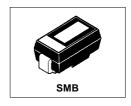
International Rectifier

MBRS130TR

SCHOTTKY RECTIFIER

1 Amp



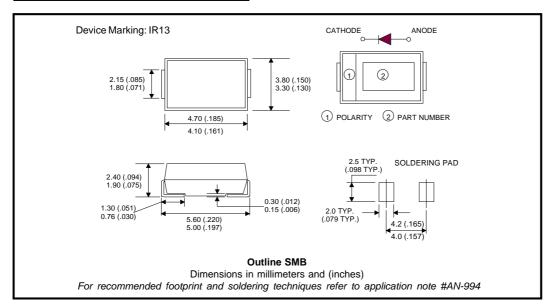
Major Ratings and Characteristics

Characteristics	MBRS130TR	Units
I _{F(AV)} Rectangular waveform	1.0	А
V _{RRM}	30	V
I _{FSM} @t _p =5μs sine	230	А
V _F @ 1.0Apk, T _J = 125°C	0.42	V
T _J range	- 55 to 125	°C

Description/ Features

The MBRS130TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



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International

TOR Rectifier

Voltage Ratings

Part number	MBRS130TR
V _R Max. DC Reverse Voltage (V)	
V _{RWM} Max. Working Peak Reverse Voltage (V)	30

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	1.0	А	50% duty cycle @ T _L = 147 °C,	rectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	870	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and
	Surge Current	50		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	3.0	mJ	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1A, L = 6\text{mH}$	
I _{AR}	Repetitive Avalanche Current	1.0	А	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. Va = 1.5 x Vr typical	

Electrical Specifications

	Parameters	Value	Units		Conditions
V_{FM}	Max. Forward Voltage Drop (1)	0.6	V	@ 1A	T ₁ = 25 °C
		0.67	V	@ 2A	1 _J = 23 0
		0.42	V	@ 1A	T,= 125 °C
		0.52	V	@ 2A	1, 120 0
I _{RM}	Max. Reverse Leakage Current	(1)	0.5	mA	T _J = 25 °C
		5.0	mA	T _J = 100 °C	V _R = rated V _R
		15	mA	T _J = 125 °C	
C _T	Max. Junction Capacitance	200	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C	
L _s	Typical Series Inductance	2.0	nΗ	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs		
	(Rated V _R)				

⁽¹⁾ Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	Value	Units	Conditions
T	Max. Junction Temperature Range (*)	-55 to 125	°C	
T _{stg}	Max. Storage Temperature Range	-55 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	25	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	DC operation
wt	Approximate Weight	0.10 (0.003)	g (oz.)	
	Case Style	SMB		Similar to DO-214AA
	Device Marking	IR13		

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{\text{dPtot}}{\text{Rth(j-a)}} < \frac{1}{\text{Rth(j-a)}} \text{ thermal runaway condition for a diode on its own heatsink}$

^(**) Mounted 1 inch square PCB

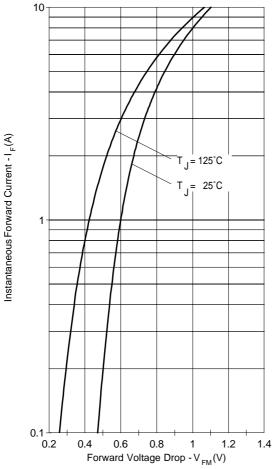


Fig. 1 - Maximum Forward Voltage Drop Characteristics

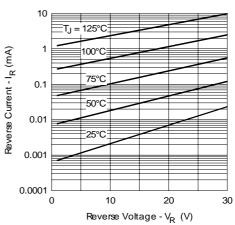


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

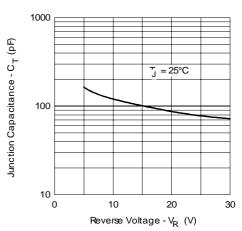


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

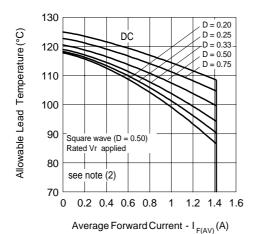


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

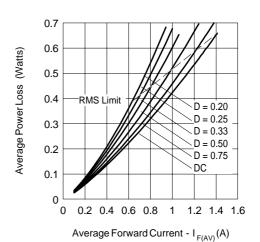


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

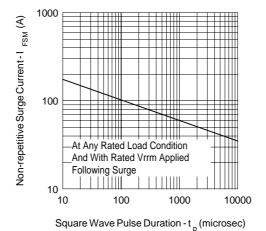
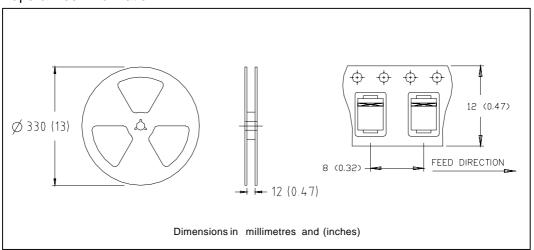


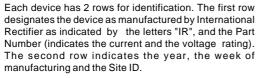
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

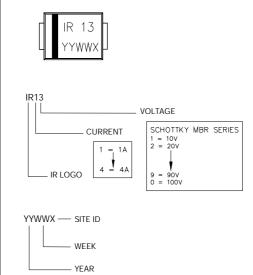
Tape & Reel Information



Marking & Identification

Ordering Information





MBRS130TR - TAPE AND REEL

WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 3000 PIECES).

EXAMPLE: MBRS130TR - 6000 PIECES

MBRS130TR

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Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.

International TOR Rectifier

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Visit us at www.irf.com for sales contact information. 03/03

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)